



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SD1618 — NPN Epitaxial Planar Silicon Transistors Low-Voltage High-Current Amplifier, Muting Applications

Features

- Low collector-to-emitter saturation voltage
- Very small size making it easy to provide highdensity, small-sized hybrid IC's

Specifications

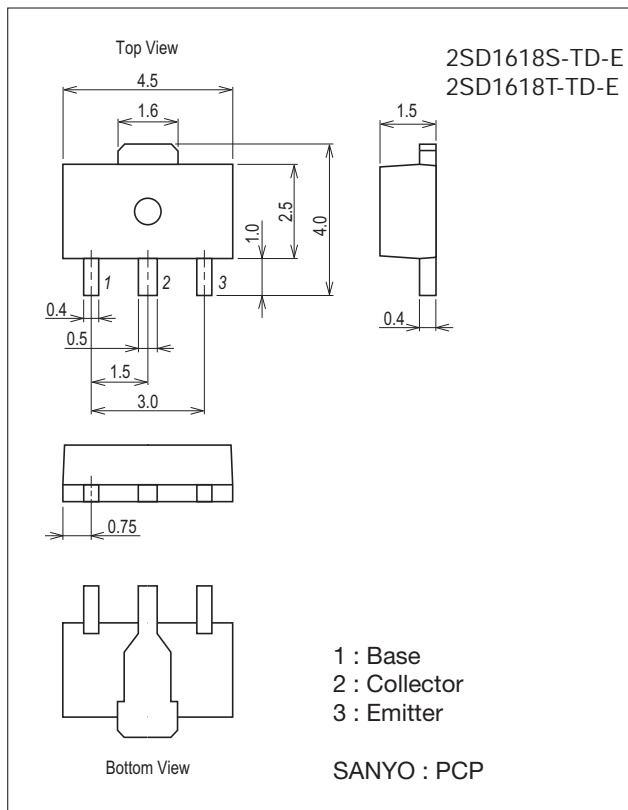
Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|--------|---|-------------|------|
| Collector-to-Base Voltage | VCBO | | 20 | V |
| Collector-to-Emitter Voltage | VCEO | | 15 | V |
| Emitter-to-Base Voltage | VEBO | | 5 | V |
| Collector Current | IC | | 0.7 | A |
| Collector Current (Pulse) | ICP | | 1.5 | A |
| Collector Dissipation | PC | | 500 | mW |
| | | When mounted on ceramic substrate (250mm ² ×0.8mm) | 1.3 | W |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Package Dimensions

unit : mm (typ)

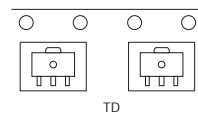
7007B-004



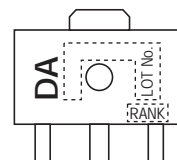
Product & Package Information

- Package : PCP
- JEITA, JEDEC : SC-62, SOT-89, TO-243
- Minimum Packing Quantity : 1,000 pcs./reel

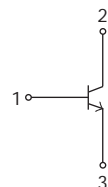
Packing Type: TD



Marking



Electrical Connection



2SD1618

Electrical Characteristics at Ta=25°C

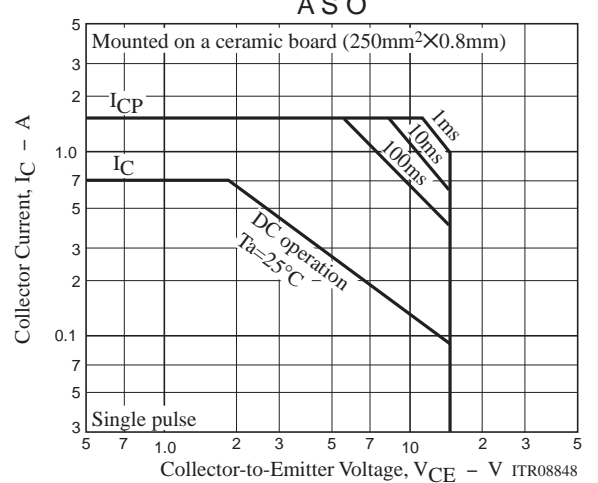
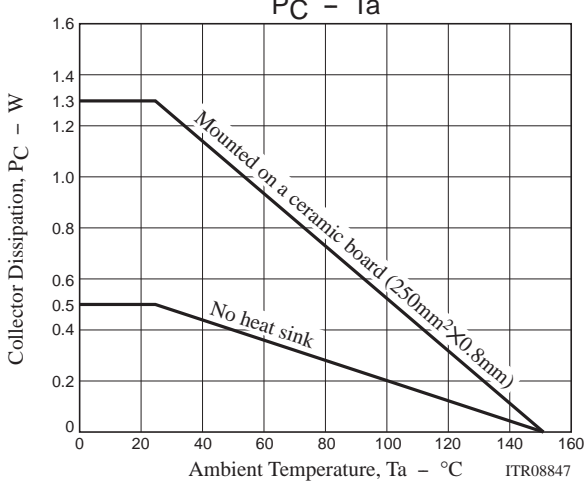
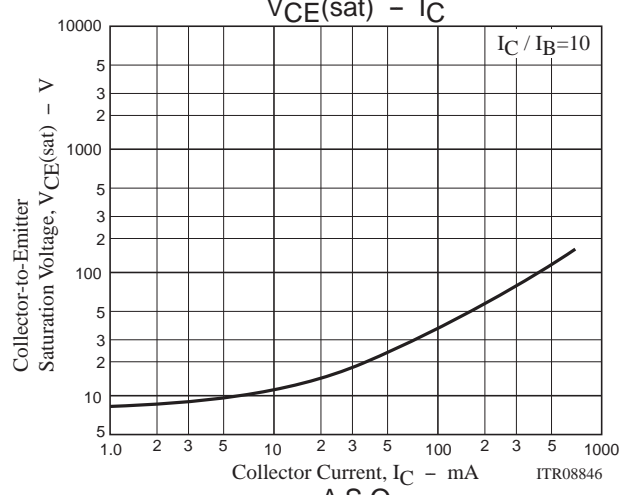
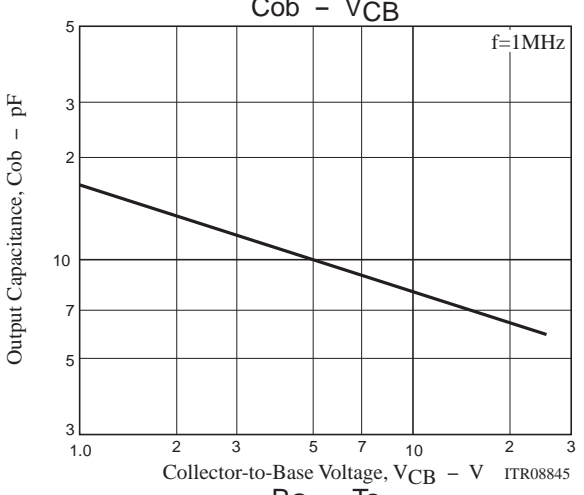
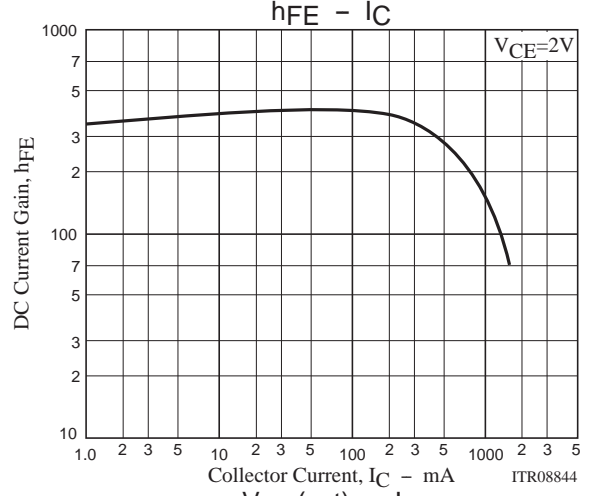
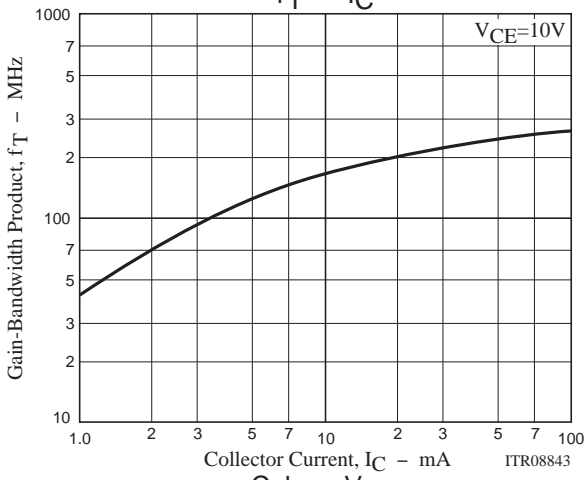
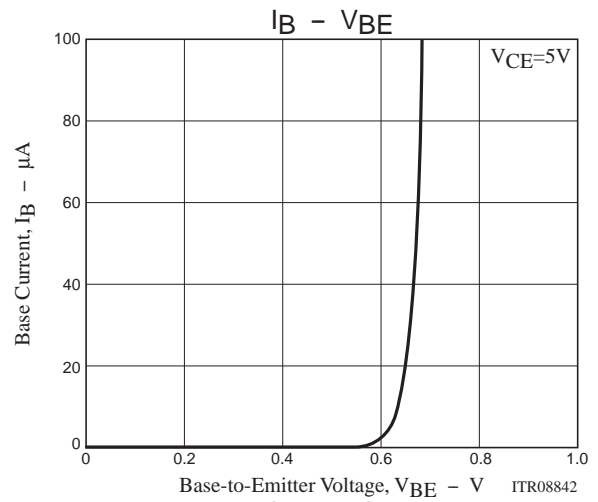
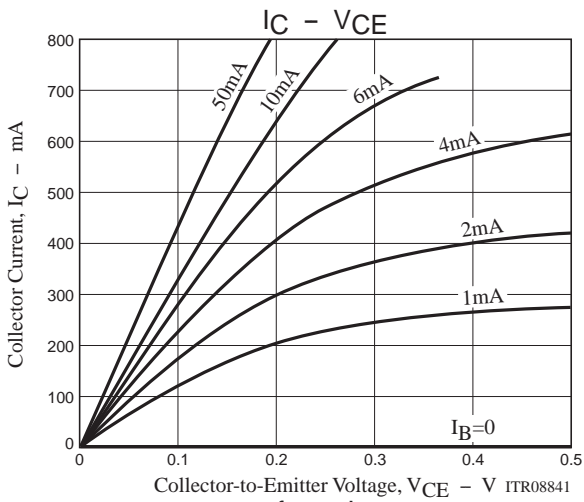
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|-----------------------|---|---------|-----|------|------|
| | | | min | typ | max | |
| Collector Cutoff Current | ICBO | V _{CB} =15V, I _E =0A | | | 0.1 | μA |
| Emitter Cutoff Current | IEBO | V _{EB} =4V, I _C =0A | | | 0.1 | μA |
| DC Current Gain | hFE1 | V _{CE} =2V, I _C =50mA | 140* | | 560* | |
| | hFE2 | V _{CE} =2V, I _C =500mA | 60 | | | |
| Gain-Bandwidth Product | f _T | V _{CE} =10V, I _C =50mA | | 250 | | MHz |
| Collector-to-Emitter Saturation Voltage | V _{CE(sat)1} | I _C =5mA, I _B =0.5mA | | 10 | 25 | mV |
| | V _{CE(sat)2} | I _C =100mA, I _B =10mA | | 30 | 80 | mV |
| Base-to-Emitter Saturation Voltage | V _{BE(sat)} | I _C =100mA, I _B =10mA | | 0.8 | 1.2 | V |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | I _C =10μA, I _E =0A | 20 | | | V |
| Collector-to-Emitter Breakdown Voltage | V(BR)CEO | I _C =1mA, R _{BE} =∞ | 15 | | | V |
| Emitter-to-Base Breakdown Voltage | V(BR)EBO | I _E =10μA, I _C =0A | 5 | | | V |
| Output Capacitance | C _{ob} | V _{CB} =10V, f=1MHz | | 8 | | pF |

* : The 2SD1618 is classified by 50mA hFE as follows :

| Rank | S | T | U |
|------|------------|------------|------------|
| hFE | 140 to 280 | 200 to 400 | 280 to 560 |

Ordering Information

| Device | Package | Shipping | memo |
|---------------|---------|----------------|---------|
| 2SD1618S-TD-E | PCP | 1,000pcs./reel | Pb Free |
| 2SD1618T-TD-E | PCP | 1,000pcs./reel | |



Bag Packing Specification

2SD1618S-TD-E, 2SD1618T-TD-E

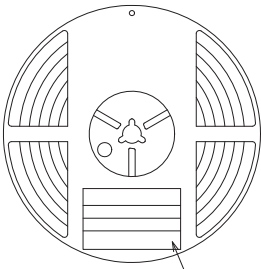
1. Packing Format

| Package Name | Carrier Tape Type | Maximum Number of devices contained (pcs) | | | Packing format | |
|--------------|-------------------|---|-----------|-----------|---|--|
| | | Reel | Inner box | Outer box | Inner BOX (C-1) | Outer BOX (A-7) |
| PCP | PCP | 1,000 | 4,000 | 24,000 | 4 reels contained Dimensions:mm (external) 183×72×185 | 6 inner boxes contained Dimensions:mm (external) 440×195×210 |

Reel label, Inner box label
(unit : mm)

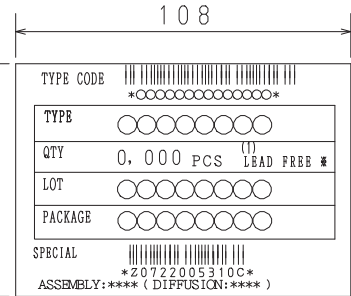
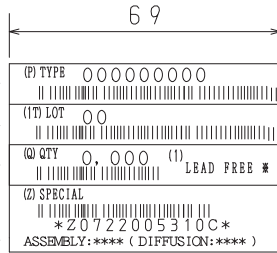
Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No. →
LOT No. →
Quantity →
Origin →



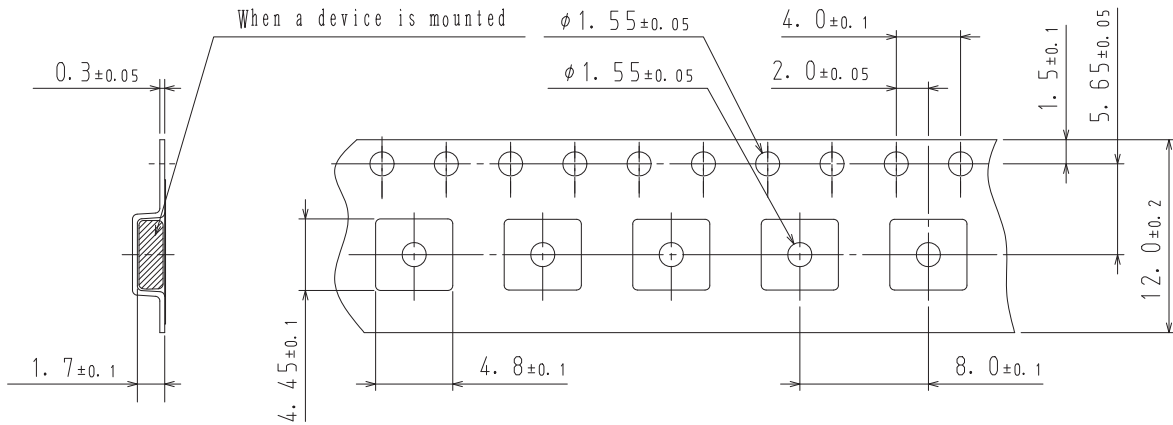
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

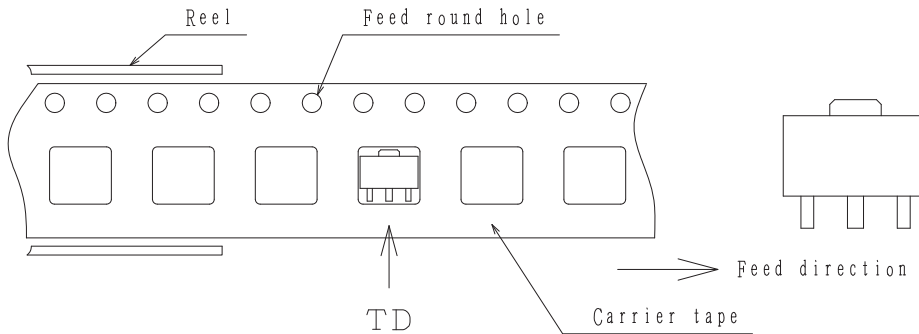
| Label | JEITA Phase |
|-------------|----------------|
| LEAD FREE 3 | JEITA Phase 3A |
| LEAD FREE 4 | JEITA Phase 3 |

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

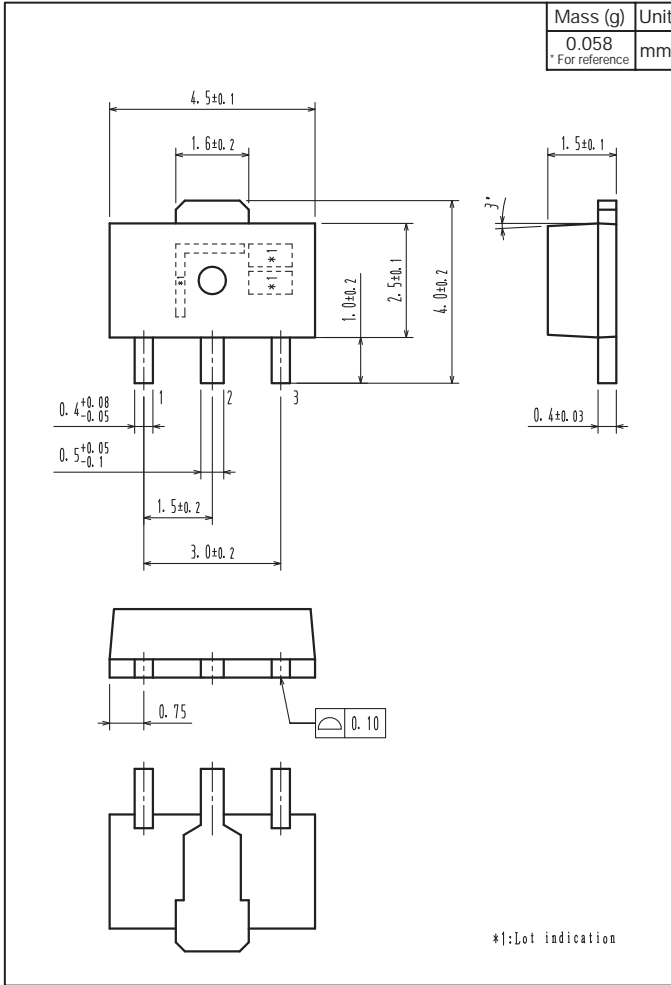


Those with pin 1 index on the feed hole side.....TD

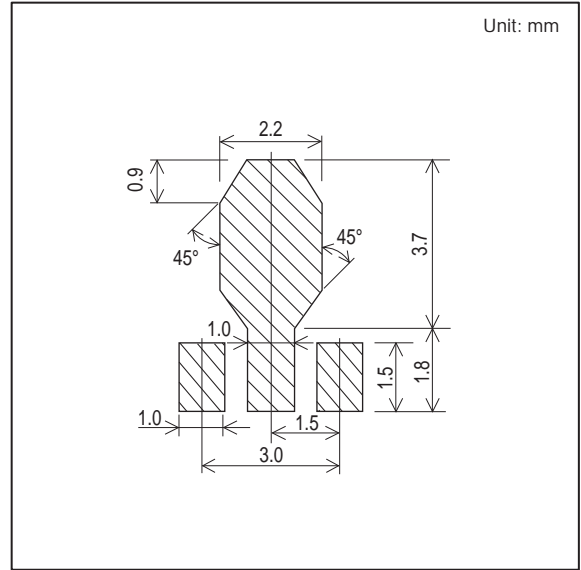
2SD1618

Outline Drawing

2SD1618S-TD-E, 2SD1618T-TD-E



Land Pattern Example



- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc. , please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- Regarding monolithic semiconductors, if you should intend to use this IC continuously under high temperature, high current, high voltage, or drastic temperature change, even if it is used within the range of absolute maximum ratings or operating conditions, there is a possibility of decrease reliability. Please contact us for a confirmation.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of August, 2012. Specifications and information herein are subject to change without notice.

This datasheet has been downloaded from:

www.DatasheetCatalog.com

Datasheets for electronic components.